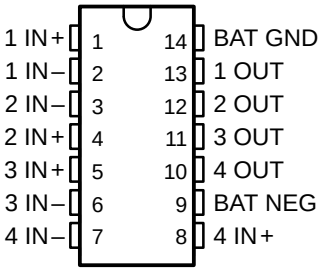
- **Designed for –52-V Battery Operation**
- **50-mA Output Current Capability**
- **Input Compatible With TTL and CMOS**
- **High Common-Mode Input Voltage Range**
- **Very Low Input Current**
- **Fail-Safe Disconnect Feature**
- **Built-in Output Clamp Diode**
- **Direct Replacement for National DS3680 and Fairchild μA3680**

D OR N PACKAGE
(TOP VIEW)

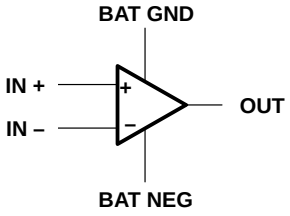


description

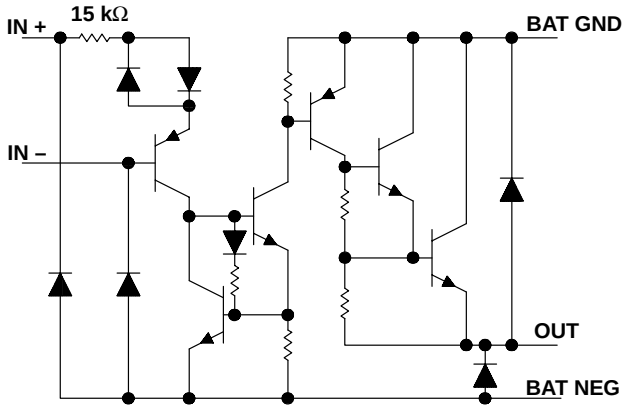
The DS3680 telephone relay driver is a monolithic integrated circuit designed to interface –48-V relay systems to TTL or other systems in telephone applications. It is capable of sourcing up to 50 mA from standard –52-V battery power. To reduce the effects of noise and IR drop between logic ground and battery ground, these drivers are designed to operate with a common-mode input range of ±20 V referenced to battery ground. The common-mode input voltages for the four drivers can be different, so a wide range of input elements can be accommodated. The high-impedance inputs are compatible with positive TTL and CMOS levels or negative logic levels. A clamp network is included in the driver outputs to limit high-voltage transients generated by the relay coil during switching. The complementary inputs ensure that the driver output is off as a fail-safe condition when either output is open.

The DS3680 is characterized for operation from 0°C to 70°C.

symbol (each driver)



schematic diagram (each driver)



All resistor values shown are nominal.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage range at BAT NEG, V_{BAT-} (see Note 1) . . . . . –70 V to 0.5 V
Input voltage range with respect to BAT GND . . . . . –70 V to 20 V
Input voltage range with respect to BAT NEG . . . . . –0.5 V to 70 V
Differential input voltage, V_{ID} (see Note 2) . . . . . ±20 V
Output current, I_O: Resistive load . . . . . –100 mA
Inductive load . . . . . –50 mA
Inductive output load . . . . . 5 H
Continuous total dissipation . . . . . See Dissipation Rating Table
Operating free-air temperature range, T_A . . . . . 0°C to 70°C
Storage temperature range, T_{stg} . . . . . –65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 60 seconds . . . . . 260°C

NOTES: 1. All voltages are with respect to BAT GND, unless otherwise specified.
2. Differential input voltages are at the noninverting input terminal IN+ with respect to the inverting input terminal IN–.

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25°C$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25°C$	$T_A = 70°C$ POWER RATING
D	950 mW	7.6 mW/°C	608 mW
N	1150 mW	9.2 mW/°C	736 mW

recommended operating conditions

	MIN	MAX	UNIT
Supply voltage, V_{BAT-}	–10	–60	V
Input voltage, either input	–20†	20	V
High-level differential input voltage, V_{IDH}	2	20	V
Low-level differential input voltage, V_{IDL}	–20†	0.8	V
Operating free-air temperature, T_A	0	70	°C

† The algebraic convention, in which the less positive (more negative) limit is designated minimum, is used in this data sheet for input voltage levels.

electrical characteristics over recommended operating free-air temperature range, V_{BAT-} = –52 V (unless otherwise noted)

PARAMETER		TEST CONDITIONS		MIN	TYP‡	MAX	UNIT
I_{IH}	High-level input current (into IN+)	V_{ID} = 2 V			40	100	µA
		V_{ID} = 7 V			375	1000	
I_{IL}	Low-level input current (into IN+)	V_{ID} = 0.4 V			0.01	5	µA
		V_{ID} = – 7 V			–1	–100	
$V_{O(on)}$	On-stage output voltage	I_O = 50 mA,	V_{ID} = 2 V		–1.6	–2.1	V
$I_{O(off)}$	Off-stage output current	$V_O = V_{BAT-}$	V_{ID} = 0.8 V		–2	–100	µA
			Inputs open		– 2	–100	
I_R	Clamp diode reverse current	V_O = 0			2	100	µA
V_{OK}	Output clamp voltage	I_O = 50 mA			0.9	1.2	V
		I_O = –50 mA,	V_{BAT-} = 0		–0.9	–1.2	
$I_{BAT(on)}$	On-state battery current	All drivers on			–2	–4.4	mA
$I_{BAT(off)}$	Off-state battery current	All drivers off			–1	–100	µA

‡ All typical values are at T_A = 25°C.

switching characteristics $V_{BAT–}$ = –52 V, T_A = 25°C

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t_{on}	Turn-on time	V_{ID} = 3-V pulse, R_L = 1 kΩ, L = 1 H, See Figure 2		1	10	µs
t_{off}	Turn-off time			1	10	µs

PARAMETER MEASUREMENT INFORMATION

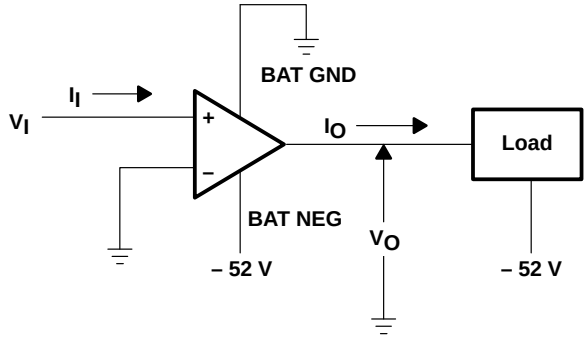


Figure 1. Generalized Test Circuit, Each Driver

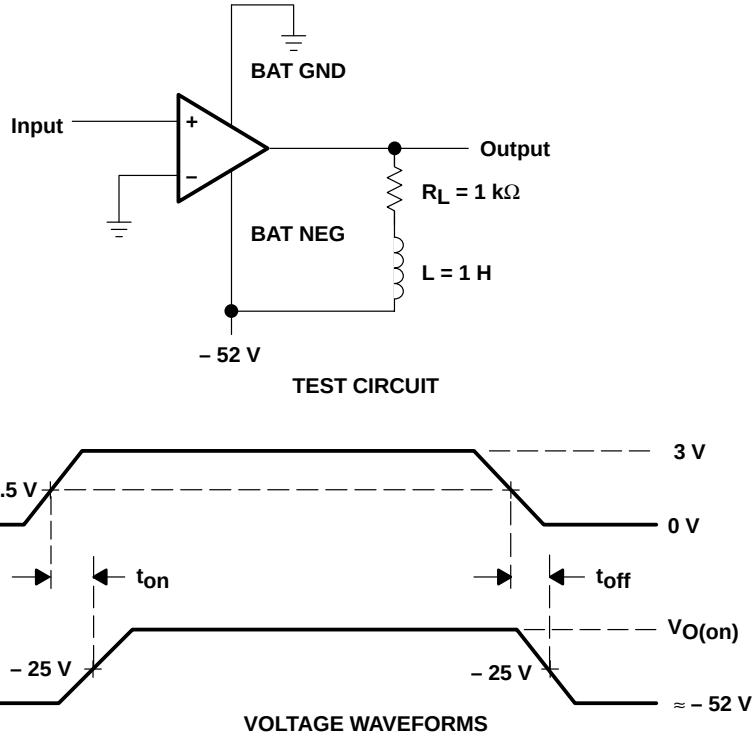


Figure 2. Test Circuit and Voltage Waveforms, Each Driver

APPLICATION INFORMATION

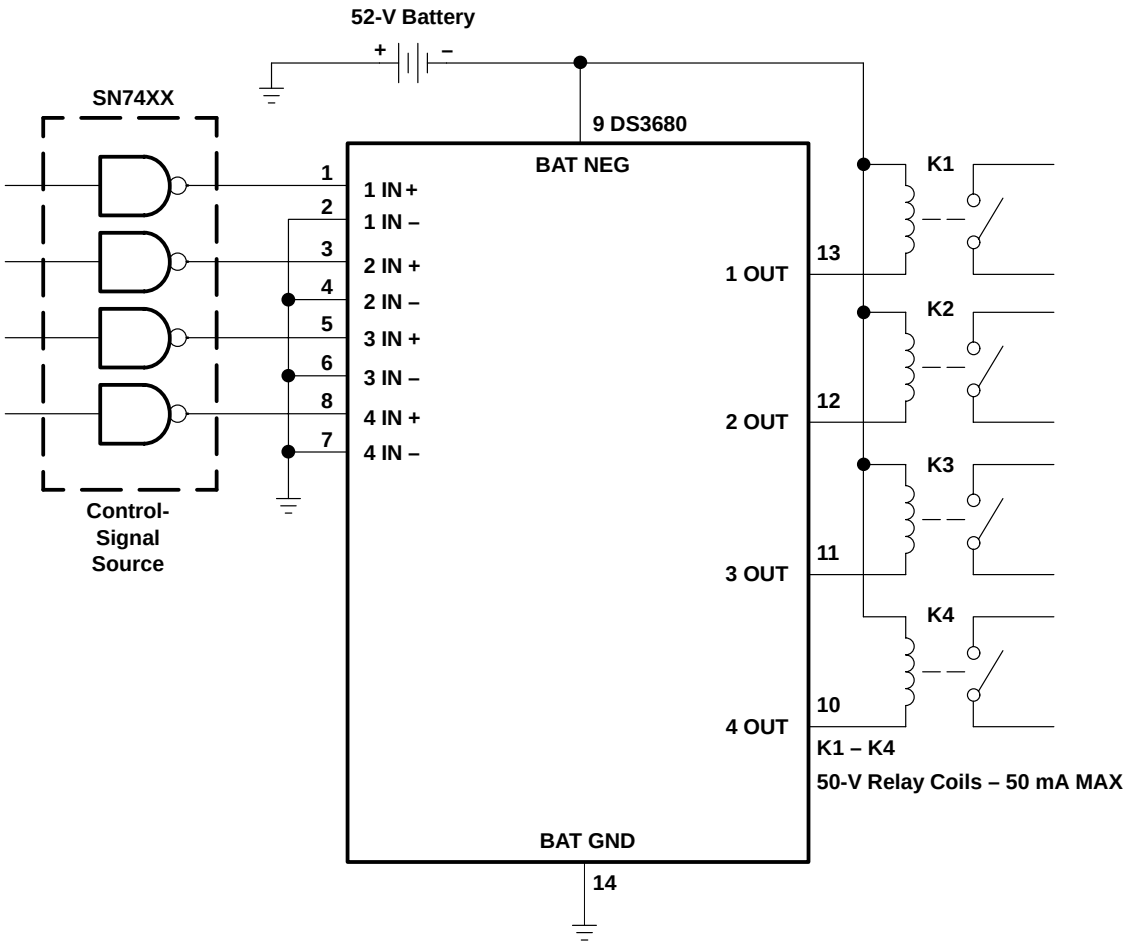


Figure 3. Relay Driver

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